

FBR2500 - FBR2510

PRV : 50 - 1000 Volts
Io : 25 Amperes

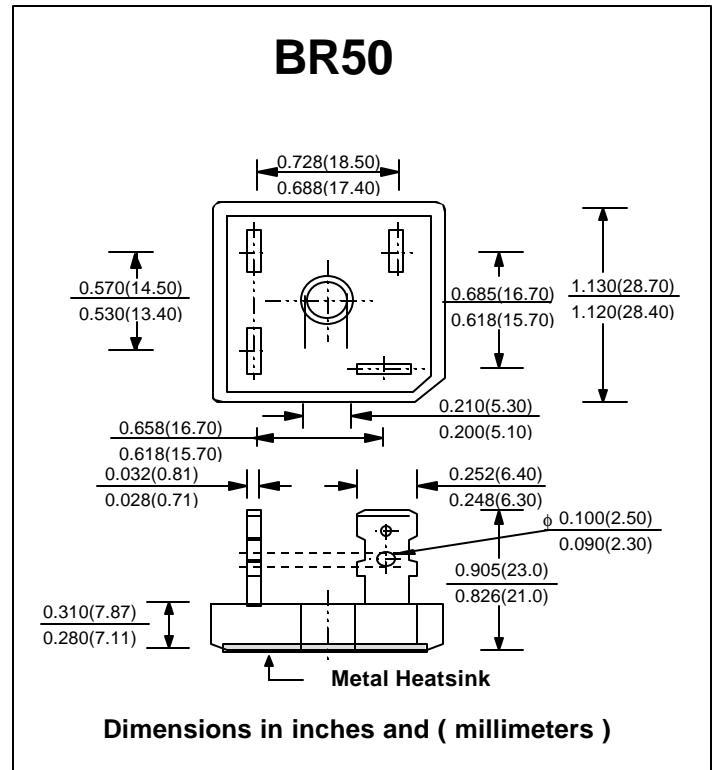
FEATURES :

- * High case dielectric strength
- * High surge current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop
- * Fast switching for high efficiency

MECHANICAL DATA :

- * Case : Molded plastic with heatsink integrally mounted in the bridge encapsulation
- * Epoxy : UL94V-O rate flame retardant
- * Terminals : plated .25" (6.35 mm). Faston
- * Polarity : Polarity symbols marked on case
- * Mounting position : Bolt down on heat-sink with silicone thermal compound between bridge and mounting surface for maximum heat transfer efficiency.
- * Weight : 17.1 grams

FAST RECOVERY BRIDGE RECTIFIERS



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

RATING	SYMBOL	FBR 2500	FBR 2501	FBR 2502	FBR 2504	FBR 2506	FBR 2508	FBR 2510	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Current $T_c = 55\text{ }^\circ\text{C}$	$I_{F(AV)}$	25							Amps.
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I_{FSM}	300							Amps.
Current Squared Time at $t < 8.3\text{ ms.}$	I^2t	375							A^2S
Maximum Forward Voltage drop per Diode at $I_F = 12.5\text{ Amps.}$	V_F	1.3							Volts
Maximum DC Reverse Current $T_a = 25\text{ }^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 100\text{ }^\circ\text{C}$	I_R	10							μA
	$I_{R(H)}$	200							μA
Maximum Reverse Recovery Time (Note 1)	T_{rr}	150			250		500		ns
Typical Thermal Resistance per diode (Note 2)	$R_{\theta JC}$	1.45							$^\circ\text{C/W}$
Operating Junction Temperature Range	T_J	- 50 to + 150							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	- 50 to + 150							$^\circ\text{C}$

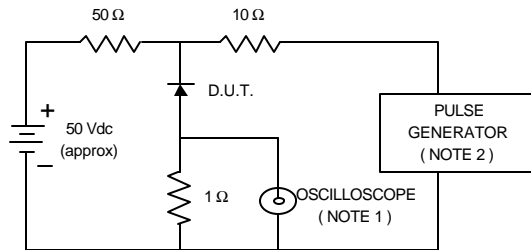
Notes :

- 1) Measured with $I_F = 0.5\text{ Amp.}$, $I_R = 1\text{ Amp.}$, $I_{rr} = 0.25\text{ Amp.}$
- 2) Thermal Resistance from junction to case with units mounted on a 5" x 6" x 4.9" (12.8cm.x 15.2cm.x 12.4cm.) Al.-Finned Plate.

UPDATE : APRIL 21, 1998

RATING AND CHARACTERISTIC CURVES (FBR2500 - FBR2510)

FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES : 1. Rise Time = 7 ns max., Input Impedance = 1 megaohm, 22 pF.
 2. Rise time = 10 ns max., Source Impedance = 50 ohms.
 3. All Resistors = Non-inductive Types.

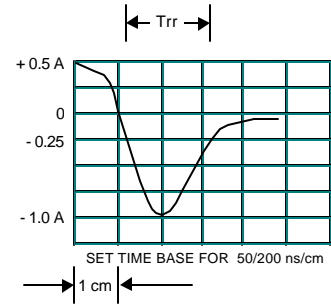


FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

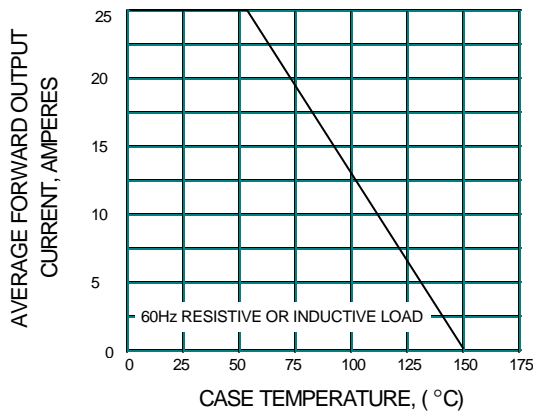


FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

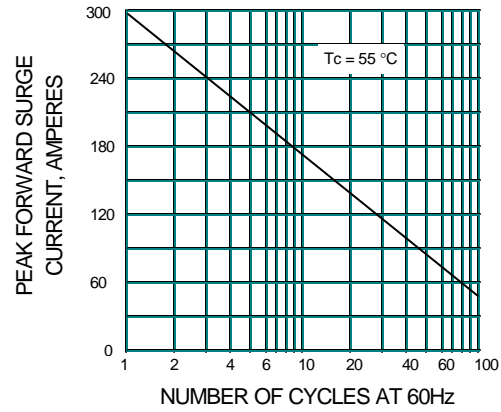


FIG.4 - TYPICAL FORWARD CHARACTERISTICS PER DIODE

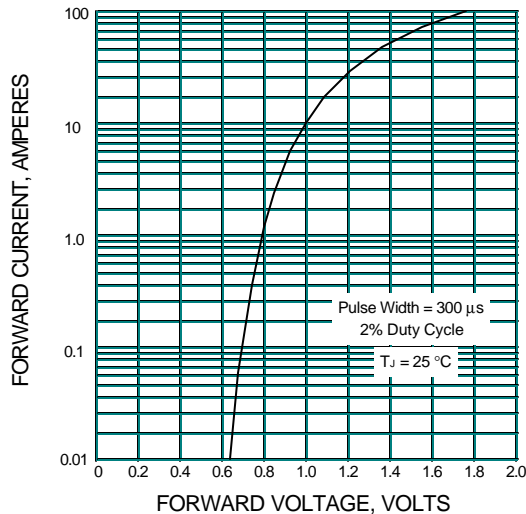


FIG.5 - TYPICAL REVERSE CHARACTERISTICS PER DIODE

